

**61113 GENERAL PURPOSE (NPN) TRANSISTOR
SURFACE MOUNT PACKAGE
(2N2369AUB)**

Mii
OPTOELECTRONIC PRODUCTS
DIVISION

Features:

- Hermetically sealed
- Hermetically sealed 3 pin LCC
- MIL-PRF-19500 screening available

Applications:

- Analog Switches
- Signal Conditioning
- Small Signal Amplifiers
- High Density Packaging

DESCRIPTION

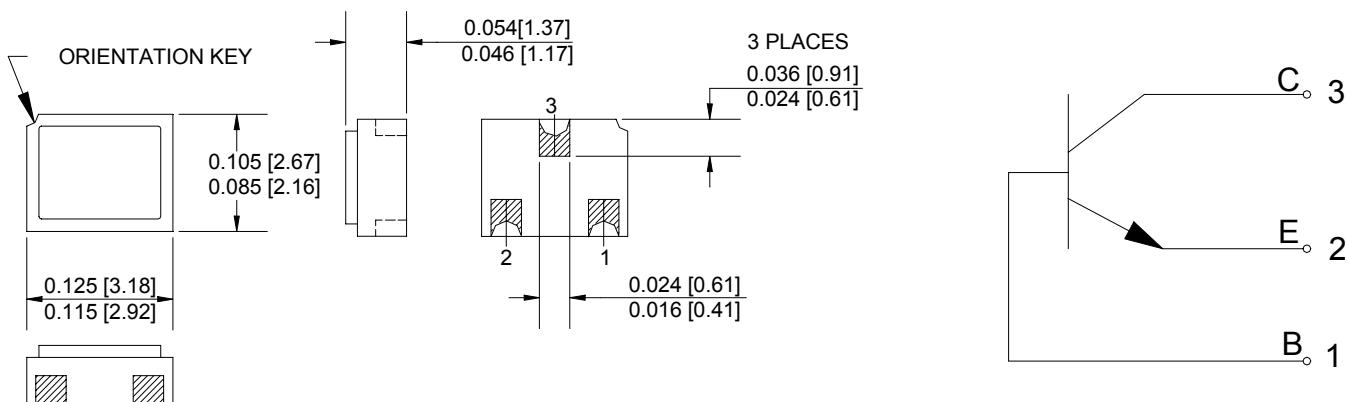
The **61113** is a N-P-N, general-purpose switching and amplifier transistor in a 3 pin leadless chip carrier package. All packages are hermetically sealed for high reliability and harsh environments. This device is available custom binned to customer specifications in commercial or screened to MIL-PRF-19500 up to JANS level.

ABSOLUTE MAXIMUM RATINGS

Collector-Base Voltage - V_{CBO}	40Vdc
Collector-Emitter Voltage - V_{CEO}	15Vdc
Collector-Emitter Voltage - V_{CES}	40Vdc
Emitter-Base Voltage - V_{EBO}	4.5Vdc
Collector Current – I_C (Peak).....	500mA
Continuous Collector Current	200mA
Maximum Junction Temperature	+200°C
Operating Temperature (See part selection guide for actual operating temperature).	-65°C to +125°C
Storage Temperature.....	-65°C to +200°C
Lead Soldering Temperature (vapor phase reflow for 30 seconds)	215°C

Package Dimensions

Schematic Diagram



ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$ unless otherwise specified.

PARAMETER	SYMBOL	MIN	MAX	UNITS	TEST CONDITIONS	NOTE
Collector-Base Breakdown Voltage	BV_{CBO}	40		V_{dc}	$I_C = 10\mu\text{A}, I_E = 0$	
Collector-Emitter Breakdown Voltage	BV_{CEO}	40		V_{dc}	$I_C = 10\mu\text{A}, I_B = 0\mu\text{A}$	
Collector-Emitter Sustaining Voltage	BV_{CES}	15		V_{dc}	$I_C = 10\text{mA}, I_B = 0\mu\text{A}$	
Emitter-Base Breakdown Voltage	BV_{EBO}	4.5		V_{dc}	$I_C = 0, I_E = 10\mu\text{A}$	
Collector-Base Cutoff Current	I_{CBO}		0.4	μA	$V_{\text{CB}} = 20\text{V}, I_E = 0$	
			30	μA	$V_{\text{CB}} = 20\text{V}, I_E = 0, T_A = 150^\circ\text{C}$	
Collector-Emitter Cutoff Current	I_{CES}		0.4	μA	$V_{\text{CE}} = 20\text{V}$	
Forward-Current Transfer Ratio	h_{fe}	-	120	-	$V_{\text{CE}} = 1\text{V}, I_C = 10\text{mA}$	
	h_{fe}	20		-	$V_{\text{CE}} = 1\text{V}, I_C = 100\text{mA}$	
	h_{fe}	20		-	$V_{\text{CE}} = 2\text{V}, I_C = 100\text{mA}$	
	h_{fe4}	20		-	$V_{\text{CE}} = 1\text{V}, I_C = 10\text{mA} @ -55^\circ\text{C}$	1
	h_{fe6}	30		-	$V_{\text{CE}} = 0.35\text{V}, I_C = 10\text{mA} @ -55^\circ\text{C}$	
Collector-Emitter Saturation Voltage	$V_{\text{CE}}(\text{SAT})$		0.20	V	$I_C = 10\text{mA}, I_B = 1\text{mA}$	1
	$V_{\text{CE}}(\text{SAT})$		0.30	V	$I_C = 10\text{mA}, I_B = 1\text{mA} @ +125^\circ\text{C}$	
	$V_{\text{CE}}(\text{SAT})$		0.25	V	$I_C = 30\text{mA}, I_B = 3\text{mA}$	
	$V_{\text{CE}}(\text{SAT})$		0.50	V	$I_C = 100\text{mA}, I_B = 10\text{mA}$	1
Base-Emitter Saturation Voltage	$V_{\text{BE}}(\text{SAT})$	0.7	0.85	V	$I_C = 10\text{mA}, I_B = 1\text{mA}$	1
	$V_{\text{BE}}(\text{SAT})$	0.59	-	V	$I_C = 10\text{mA}, I_B = 1\text{mA} @ +125^\circ\text{C}$	
	$V_{\text{BE}}(\text{SAT})$		1.02	V	$I_C = 10\text{mA}, I_B = 1\text{mA} @ -55^\circ\text{C}$	
	$V_{\text{BE}}(\text{SAT})$		1.15	V	$I_C = 30\text{mA}, I_B = 3\text{mA}$	
	$V_{\text{BE}}(\text{SAT})$		1.60	V	$I_C = 100\text{mA}, I_E = 10\text{mA}$	1

SMALL-SIGNAL CHARACTERISTICS

Current-Gain – Bandwidth Product	f_r	500		MHz	$V_{\text{CB}} = 10\text{V}, 100\text{kHz}, \leq f \leq 1\text{ MHz}$	
Input Capacitance (Output Open Capacitance)	C_{IBO}		25	pF	$V_{\text{EB}} = 0.5\text{ V}, 100\text{kHz}, \leq f \leq 1\text{ MHz}$	
Turn-On Time	t_{on}		35	nS	$V_{\text{CC}} = 30\text{V}, I_C = 150\text{mA}, I_{B1} = 15\text{mA}$	
Turn-Off Time	t_{off}		300	nS	$V_{\text{CC}} = 30\text{V}, I_C = 150\text{mA}, I_{B1} = I_{B2} = 15\text{mA}$	

NOTES:

1. Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2.0\%$.

SELECTION GUIDE

PART NUMBER	PART DESCRIPTION
61113-001	2N2369AUB PNP transistor, commercial version
61113-002	2N2369AUB PNP transistor, JAN level screening
61113-003	2N2369AUB PNP transistor, JANTX level screening
61113-004	2N2369AUB PNP transistor, JANTXV level screening
61113-005	2N2369AUB PNP transistor, JANS level screening

NOTE: Also available in dual and quad configurations upon request. Can also be supplied in gull wing surface mount versions.